

October 1987

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MM82C19 16-Line to 1-Line Multiplexer

FAIRCHILD

SEMICONDUCTOR

MM82C19 16-Line to 1-Line Multiplexer

General Description



The MM82C19 multiplex 16 digital lines to 1 output. A 4-bit address code determines the particular 1-of-16 inputs which is routed to the output. The data is inverted from input to output.

A strobe override places the output of MM82C19 in the high-impedance state.

All inputs are protected from damage due to static discharge by diode clamps to V_{CC} and GND.

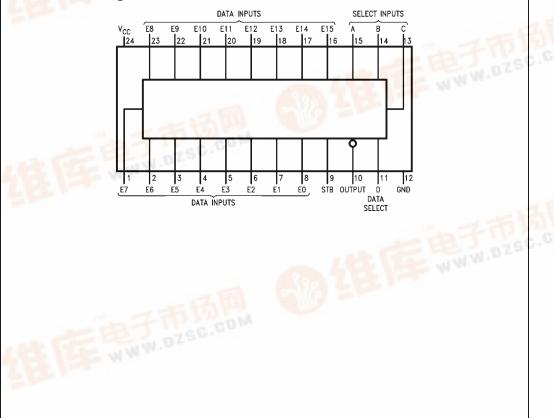
Features

- Wide supply voltage range: 3.0V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45 V_{CC} (typ.)
- TTL compatibility: Drive 1 TTL Load

Ordering Code:

Order Number	Package Number	Package Description
MM82C19N	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-011, 0.600" Wide

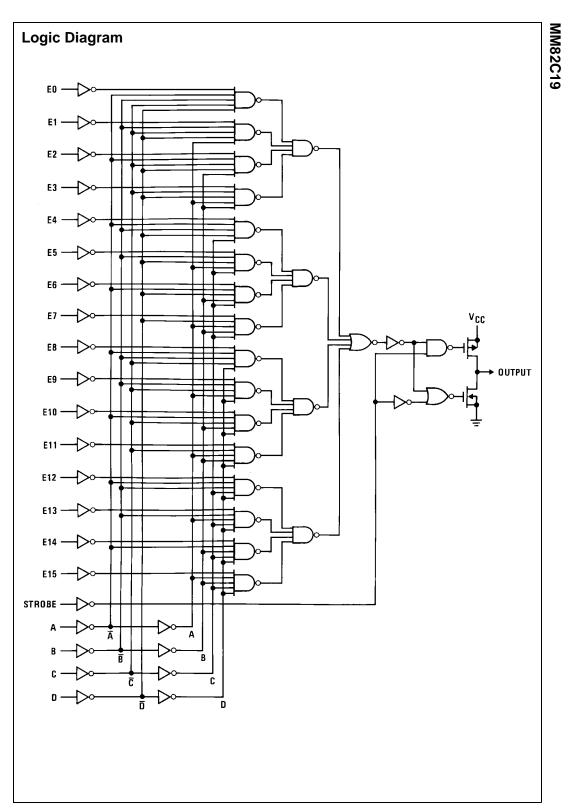
Connection Diagram





MM82C19

Tru	uth	Ta	abl	е																	
										MN	/82C	19									
									I	nput	S									Ī	Output
D	С	в	Α	STROBE	E0	E1	E2	E3	E4	E5	E6	E7	E8	E9	E10	E11	E12	E13	E14	E15	w
Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	High-Z
0	0	0	0	0	0	Х	х	Х	х	х	Х	Х	Х	Х	х	х	х	х	х	х	1
0	0	0	0	0	1	Х	х	Х	х	х	Х	Х	Х	Х	Х	Х	Х	х	х	х	0
0	0	0	1	0	х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	Х	Х	х	х	1
0	0	0	1	0	х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	0
0	0	1	0	0	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	1
0	0	1	0	0	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	0
0	0	1	1	0	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	1
0	0	1	1	0	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	0
0	1	0	0	0	Х	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	1
0	1	0	0	0	Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0
0	1	0	1	0	Х	Х	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1
0	1	0	1	0	Х	Х	Х	Х	Х	1	X	Х	Х	X	Х	Х	Х	Х	Х	X	0
0	1	1	0	0	X	X	X	X	X	X	0	X	X	X	X	X	X	X	X	X	1
0	1	1	0	0	X	X	X	X	X	X	1	X	X	X	X	X	X	X	X	X	0
0	1 1	1 1	1 1	0	X X	0 1	X X	1 0													
1	0	0	0	0	x	x	x	x	x	x	x	X	0	x	X	X	X	X	x	x	1
1	0	0	0	0	x	x	X	x	X	X	x	x	1	x	X	X	X	X	X	x	0
1	0	0	1	0	X	x	X	x	X	X	x	x	x	0	X	X	X	X	X	x	1
1	0	0	1	0	X	Х	x	Х	X	Х	Х	Х	Х	1	X	Х	X	x	X	x	0
1	0	1	0	0	х	х	х	х	х	х	х	Х	Х	х	0	х	х	х	Х	х	1
1	0	1	0	0	х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	х	х	х	х	х	0
1	0	1	1	0	х	Х	х	Х	х	х	Х	Х	Х	Х	х	0	х	х	х	х	1
1	0	1	1	0	х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	1	Х	х	х	х	0
1	1	0	0	0	х	Х	х	Х	х	х	Х	Х	Х	Х	Х	Х	0	Х	Х	х	1
1	1	0	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	Х	Х	х	0
1	1	0	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0	Х	х	1
1	1	0	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	Х	х	0
1	1	1	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0	х	1
1	1	1	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	х	0
1	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0	1
1	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	0



Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	–0.3V to V _{CC} + 0.3V
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V _{CC} Range	3.0V to 15V
V _{CC}	18V
Lead Temperature	
(soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristic table provides conditions for actual device operation.

DC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS to 0	MOS					
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5.0V$	3.5			V
		$V_{CC} = 10V$	8.0			v
V _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5.0V$			1.5	V
		$V_{CC} = 10V$			2.0	v
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} = -10 \ \mu A$	4.5			V
		$V_{CC} = 10V, I_{O} = -10 \ \mu A$	9.0			v
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_{O} = +10 \ \mu A$			0.5	V
		$V_{CC} = 10V, I_{O} = +10 \ \mu A$			1.0	v
I _{IN(1)}	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15V		0.005	1.0	V
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μΑ
loz	Output Current in High					
	Impedance State					
	MM82C19	$V_{CC} = 15V, V_{O} = 15V$		0.005	1.0	μΑ
		$V_{CC} = 15V, V_{O} = 0V$	-1.0	-0.005		
I _{CC}	Supply Current	$V_{CC} = 15V$		0.05	300	μΑ
CMOS/LP1	TL Interface	·				
V _{IN(1)}	Logical "1" Input Voltage	74C, 82C, V _{CC} = 4.75V	V _{CC} -1.5			V
V _{IN(0)}	Logical "0" Input Voltage	74C, 82C, V _{CC} = 4.75V			0.8	V
V _{OUT(1)}	Logical "1" Output Voltage	74C, 82C, $V_{CC} = 4.75V$, $I_{O} = -1.6$ mA	2.4			V
V _{OUT(0)}	Logical "0" Output Voltage	74C, 82C, $V_{CC} = 4.75V$, $I_{O} = 1.6$ mA			0.4	V
Output Dri	ve (Short Circuit Current)	·				
ISOURCE	Output Source Current	$V_{CC} = 5.0V, V_{OUT} = 0V, T_A = 25^{\circ}C$	-4.35	-8		mA
	(P-Channel)					
ISOURCE	Output Source Current	$V_{CC} = 10V$, $V_{OUT} = 0V$, $T_A = 25^{\circ}C$	-20	-40		mA
	(P-Channel)					
I _{SINK}	Output Sink Current	$V_{CC} = 5.0V$, $V_{OUT} = V_{CC}$, $T_A = 25^{\circ}C$	4.35	8		mA
	(N-Channel)					
I _{SINK}	Output Sink Current	V_{CC} = 10V, V_{OUT} = V_{CC} , T_A = 25°C	20	40		mA
	(N-Channel)					

Symbol	Parameter	Conditions	Min	Тур	Max	Units			
t _{pd0} , t _{pd1}	Propagation Delay Time to a	V _{CC} = 5.0V		250	600				
	Logical "0" or Logical "1"	$V_{CC} = 10V$	110 300						
	from Data Inputs to Output	$V_{CC} = 5.0V, C_L = 150 \text{ pF}$		290	650	ns			
		$V_{CC} = 10V, C_{L} = 150 \text{ pF}$		120	330				
t _{pd0} , t _{pd1}	Propagation Delay Time to a	$V_{CC} = 5.0V$		290	650	ns			
	Logical "0" or Logical "1"	$V_{CC} = 10V$		120	330	115			
	from Data Select Inputs to Output								
t _{pd0} , t _{pd1}	Propagation Delay Time to a	$V_{CC} = 5.0V$		120	300	ns			
	Logical "0" or Logical "1"	$V_{CC} = 10V$		55	150	115			
	from Strobe to Output MM74C150								
t _{1H} , t _{OH}	Delay from Strobe to High	$V_{CC} = 5.0V, R_L = 10k, C_L = 5 \text{ pF}$		80	200	ns			
	Impedance State MM82C19	$V_{CC} = 10V, R_L = 10k, C_L = 5 \text{ pF}$		60	150	ns			
t _{H1} , t _{H0}	Delay from Strobe to Logical	Strobe to Logical $V_{CC} = 5.0V, R_L = 10k, C_L = 5 pF$ 80							
	"1" Level or to Logical "0"	$V_{CC} = 10V, R_L = 10k, C_L = 5 \text{ pF}$		30	120	ns			
	Level (from High Impedance State)								
	MM82C19								
C _{IN}	Input Capacitance	Any Input (Note 3)		5.0		pF			
C _{OUT}	Output Capacitance	(Note 3)		11.0		pF			
	MM82C19								
C _{PD}	Power Dissipation Capacitance	(Note 4)		100		pF			

Note 2: AC Parameters are guaranteed by DC correlated testing.

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation, see Family Characteristics, application note AN-90.

MM82C19

